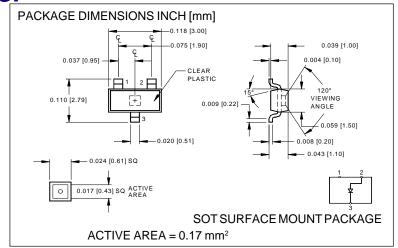
**PHOTONIC**Silicon Photodiode, Blue Enhanced Photoconductive surface mount packageType PDB-C150SM





### **FEATURES**

- Surface mount
- Low cost
- Tape and reeled
- High speed

#### **DESCRIPTION**

The **PDB-C150SM** is a silicon, PIN planar diffused, blue enhanced photodiode. Ideal for high speed photoconductive applications. Packaged in water clear SOT, surface mount package.

#### **APPLICATIONS**

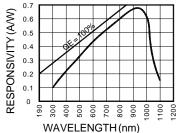
- Floppy disk drives
- Industrial controls
- Opto switches
- Opto counters

## ABSOLUTE MAXIMUM RATING (TA=25°C unless otherwise noted)

SYMBOL	PARAMETER	MIN	MAX	UNITS
V <sub>BR</sub>	Reverse Voltage		50	V
T <sub>STG</sub>	Storage Temperature	-40	+125	∘C
To	Operating Temperature Range	-40	+80	∘C
Ts	Soldering Temperature*		+240	∘C
IL	Light Current		500	mA

<sup>\*1/16</sup> inch from case for 3 secs max

### **SPECTRAL RESPONSE**



# ELECTRO-OPTICAL CHARACTERISTICS (TA=25°C unless otherwise noted)

(								
SYMBOL	CHARACTERISTIC	TESTCONDITIONS	MIN	TYP	MAX	UNITS		
Isc	Short Circuit Current	H = 1000 Lux, 2850 K	1.0	2		μΑ		
ΙD	Dark Current	H = 0, V <sub>R</sub> = 10 V		2	30	nA		
Rsн	Shunt Resistance	H = 0, V <sub>R</sub> = 10 mV		100		МΩ		
TC RsH	RsH Temp. Coefficient	H = 0, V <sub>R</sub> = 10 mV		-8		%/℃		
C¹	Junction Capacitance	H = 0, V <sub>R</sub> = 0 V**		1	5	pF		
λrange	Spectral Application Range	Spot Scan	400		1100	nm		
λр	Spectral Response - Peak	Spot Scan		950		nm		
VBR	Breakdown Voltage	I = 10 μA	30	100		V		
NEP	Noise Equivalent Power	V <sub>R</sub> = 10 V @ Peak		2.5x10 <sup>-15</sup>		W/ √Hz		
tr	Response Time	RL = 1 KΩ V <sub>R</sub> = 10 V		6.0		nS		

Information in this technical data sheet is believed to be correct and reliable. However, no responsibility is assumed for possible inaccuracies or omission. Specifications are subject to change without notice. \*\*f=1 MHz